

	<h2 style="color: red;">SI1016X-T1-GE3</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">SI1016X-T1-GE3</a>
	<b>Hersteller / Marke:</b>	<a href="#">Vishay / Siliconix</a>
	<b>Teil der Beschreibung:</b>	MOSFET N/P-CH 20V SC89-6
<b>Datenblätter:</b>	 <a href="#">SI1016X-T1-GE3.pdf</a>	
<b>RoHs Status:</b>	Bleifrei / RoHS-konform	
<b>Lagerzustand:</b>	New original, 198528 pcs Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Spezifikationen

Teilenummer	<a href="#">SI1016X-T1-GE3</a>
Hersteller	<a href="#">Vishay / Siliconix</a>
Beschreibung	MOSFET N/P-CH 20V SC89-6
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	198528 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	250mW
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SC-89-6
Typ FET	N and P-Channel
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	485mA, 370mA
Rds On (Max) @ Id, Vgs	700 mOhm @ 600mA, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	0.75nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)
















































SI1016X-T1-GE3 ist neu im Original, Suche SI1016X-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1016X-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1016X-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI1020-A-GM</b> Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM&lt;1GHZ 85-VFLGA</p>	 <p><b>SI1016X</b> VISHAY SI1016X VISHAY</p>	 <p><b>SI1016X-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V SOT563F</p>	 <p><b>SI1016X-T1-E3</b> Vishay / Siliconix MOSFET N/P-CH 20V SOT563F</p>
 <p><b>SI1016X-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V SC89-6</p>	 <p><b>SI1020-915-A-DK</b> Energy Micro (Silicon Labs) KIT DEV WIRELESS SI1020 915MHZ</p>	 <p><b>SI1016CX-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N/P-CH 20V SC89-6</p>	 <p><b>SI1020-915-A-SDK</b> Energy Micro (Silicon Labs) KIT SOFTWARE DEV SI1020 915MHZ</p>

### heiße Teile

Mehr

 SI1012R-T1-E3	 SI1012R-T1-GE3	 SI1012R-T1-GE3	 SI1012X-T1	 SI1012X-T1-E3
 SI1012X-T1-E3	 SI1012X-T1-GE3	 SI1012X-T1-GE3	 SI1013CX-T1-GE3	 SI1013CX-T1-GE3
 SI1013R-T1	 SI1013R-T1-E3	 SI1013R-T1-E3	 SI1013R-T1-GE3	 SI1013R-T1-GE3
 SI1013X-T1	 SI1013X-T1-E3	 SI1013X-T1-E3	 SI1013X-T1-GE3	 SI1013X-T1-GE3
 SI1016CX-T1-GE3	 SI1016CX-T1-GE3	 SI1016X-T1-E3	 SI1016X-T1-E3	 SI1016X-T1-GE3
 SI1016X2-T1-GE3	 SI1021R-T1	 SI1021R-T1-E3	 SI1021R-T1-E3	 SI1022R-T1
 SI1022R-T1-E3	 SI1022R-T1-E3	 SI1022R-T1-GE3	 SI1022R-T1-GE3	 SI1022R-T1-E3
 SI1023CX-T1-GE3	 SI1023CX-T1-GE3	 SI1023X-T1	 SI1023X-T1-E3	 SI1023X-T1-E3
 SI1023X-T1-GE3	 SI1023X-T1-GE3	 SI1024-T1	 SI1024X-T1	 SI1024X-T1-E3
 SI1024X-T1-E3	 SI1024X-T1-GE3	 SI1024X-T1-GE3	 SI1024X-T1-GE3	 SI1025X-T1

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